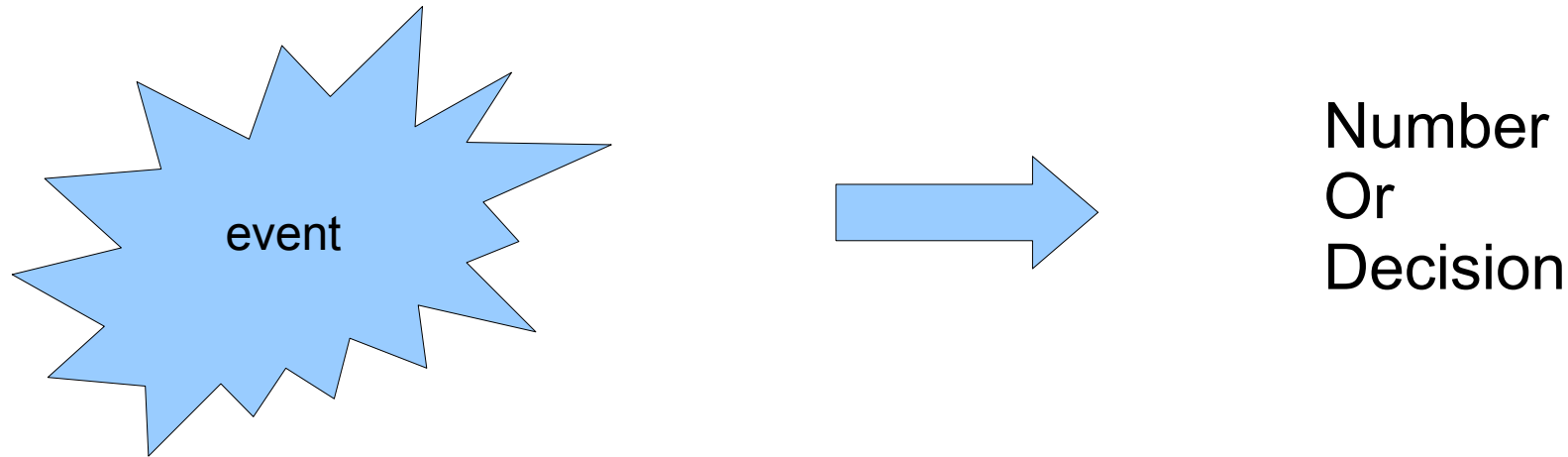


Nuclear electronics

A simple introduction to some basic aspects of
the analogue front end part of detector
electronics

Patrick Van Esch (ILL)

Detection, current, charge I



Physical detection → movement of charges in strong E field

Induction of currents in conductors (electrodes)

Most other instrumentation:

Change in impedance

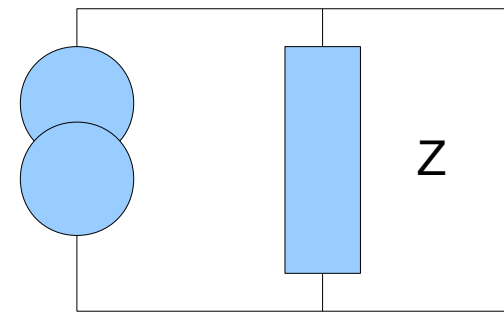
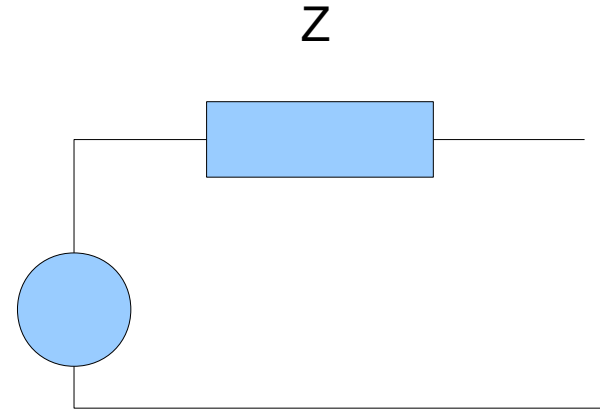
Change in electro(chemical) potential

Thevenin and Norton

A « source » is represented by an electric circuit, which can be simplified as:

An imperfect voltage source (Thevenin)

An imperfect current source (Norton)



Amplifiers

Amplifiers are « matched » to sources.

Ideal voltage sources with ideal voltage amplifiers

Ideal current sources with ideal current amplifiers

Voltage amplifier: high impedance

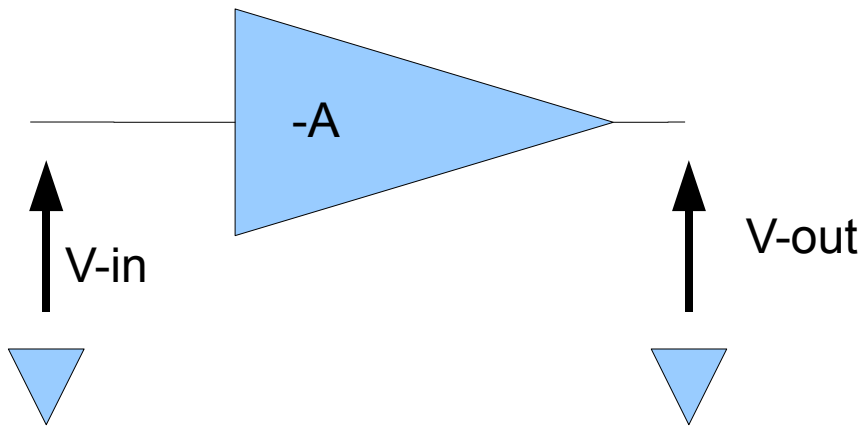
Current amplifier: low impedance

In fact, the output is always a voltage:

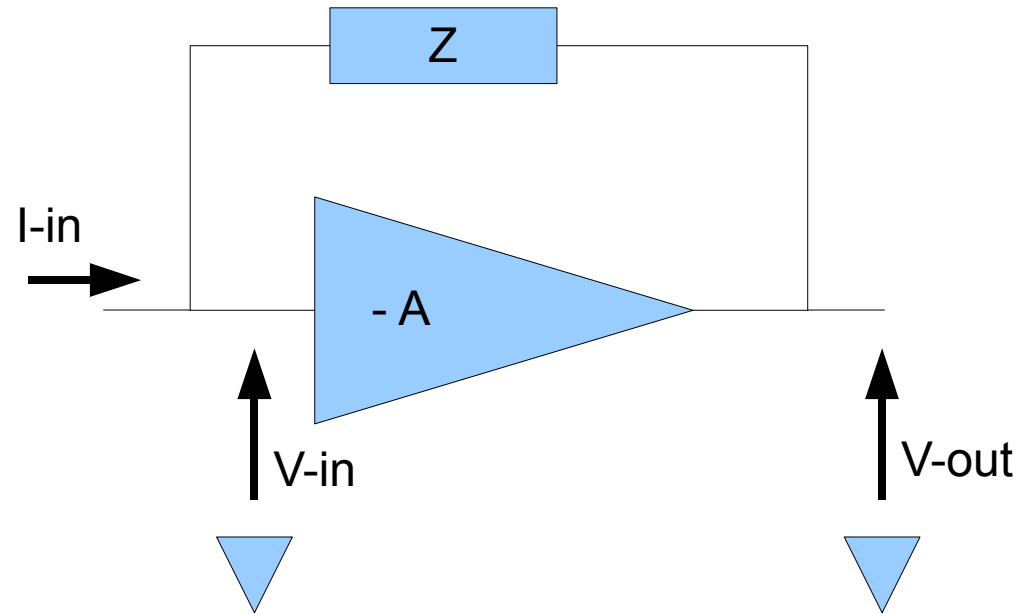
Voltage – voltage amplifier (« normal » amplifier)

Current – voltage amplifier (transimpedance amp.)

How to make a transimpedance amplifier ?



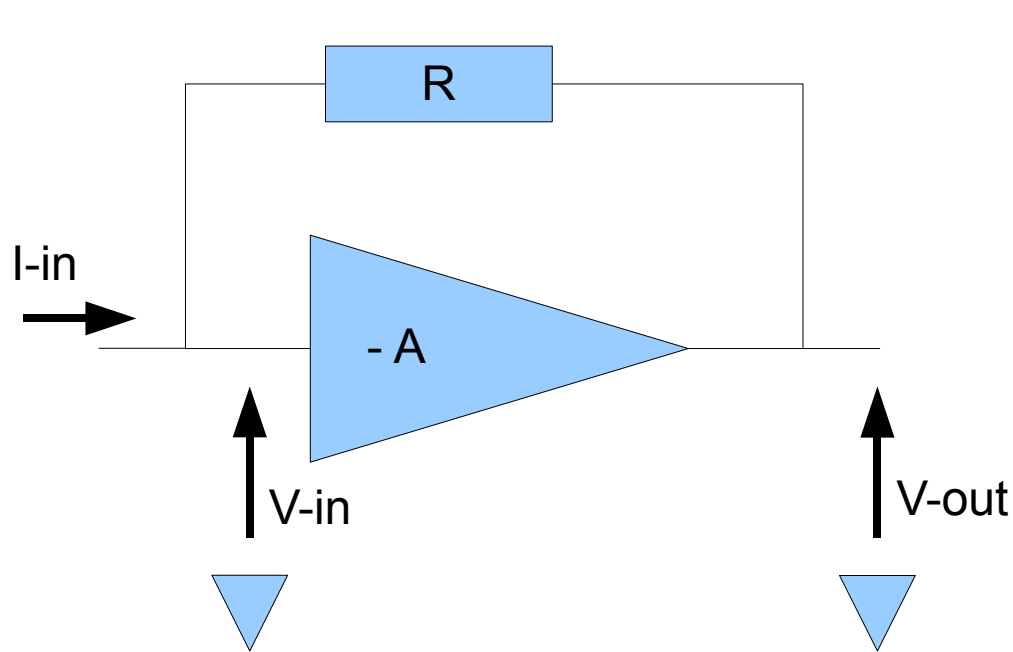
$$V_{out} = -A V_{in}$$



$V_{out} = -A V_{in}$;
 $V_{in} - V_{out} = I_{in} Z$;
A very big, hence V_{in} much smaller than V_{out} , hence:

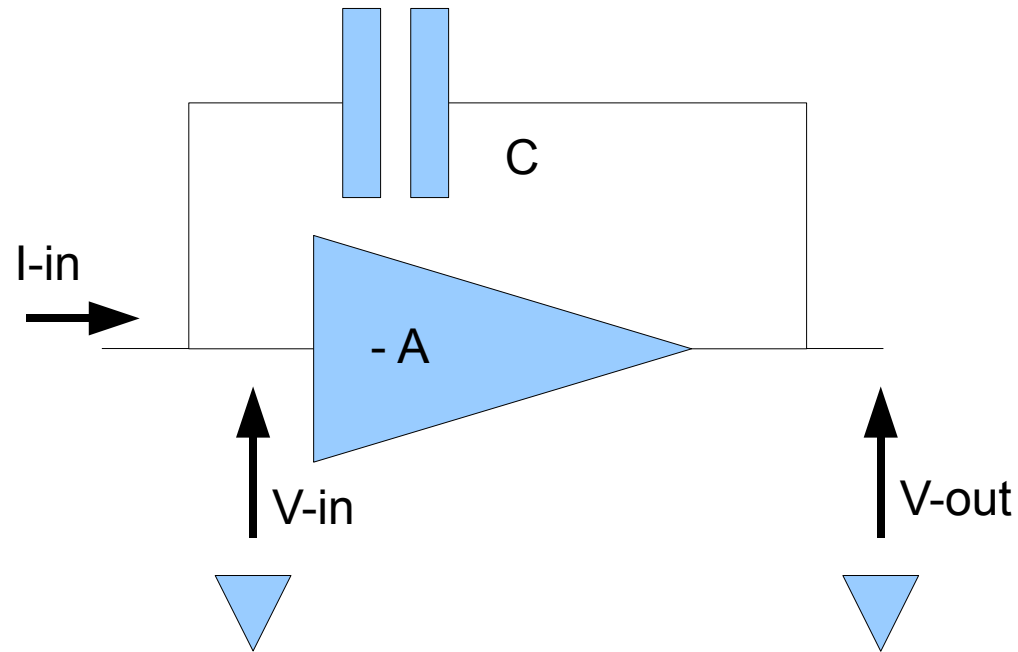
$$V_{out} = -Z I_{in}$$

« Current » vs. « Charge »



$$V_{out}(s) = -R I_i(s)$$

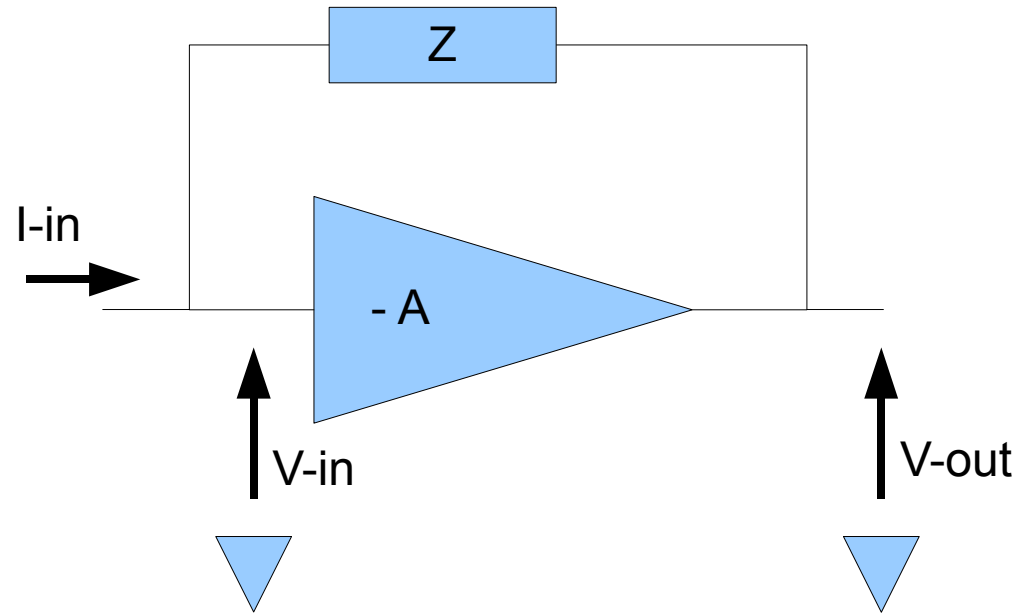
$$v_{out}(t) = -R i_i(t)$$



$$V_{out}(s) = \frac{-1}{s \cdot C} I_i(s)$$

$$V_{out}(t) = \frac{-1}{C} \int i_i(t) dt = \frac{-Q(t)}{C}$$

Input impedance



$$V_i = V_{out} + i_i \cdot Z$$

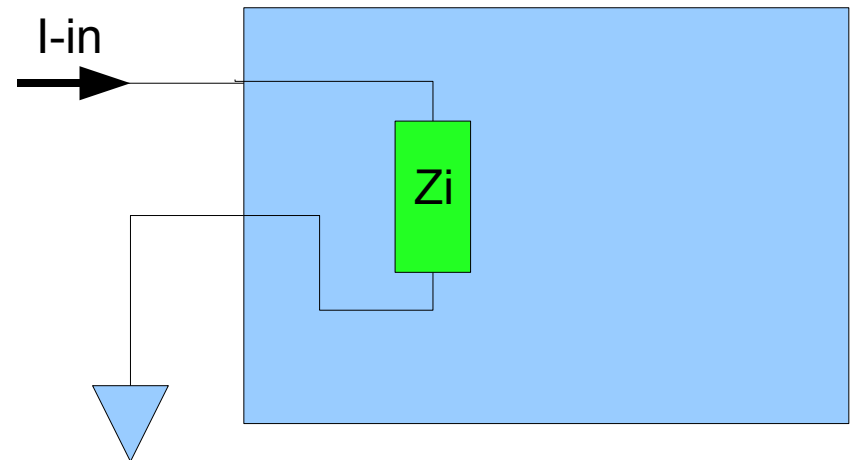
$$V_{out} = -A V_i$$

$$V_i = -A V_i + i_i Z$$

$$Z_i = -A \cdot Z_i + Z$$

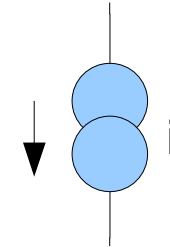
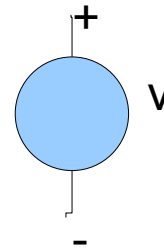
$$(1 + A) Z_i = Z$$

$$Z_i = \frac{Z}{A + 1}$$



Noise sources I

Represented by voltage or current sources



V or I is a random process with average 0 and given autocorrelation.

$$f(t_1) = X_1; f(t_2) = X_2$$

$$\langle X_1 \rangle = 0$$

$$R(\tau) = \langle X_1 X_2 \rangle; \tau = t_2 - t_1$$

$$R(0) = \langle X_1^2 \rangle = f_{rms}^2$$

Wiener-Khinchine:
power spectral density (one-sided)

$$S(f) = 4 \int_{\tau=0}^{\infty} R(\tau) \cos(2\pi f \tau) d\tau$$

Noise sources II

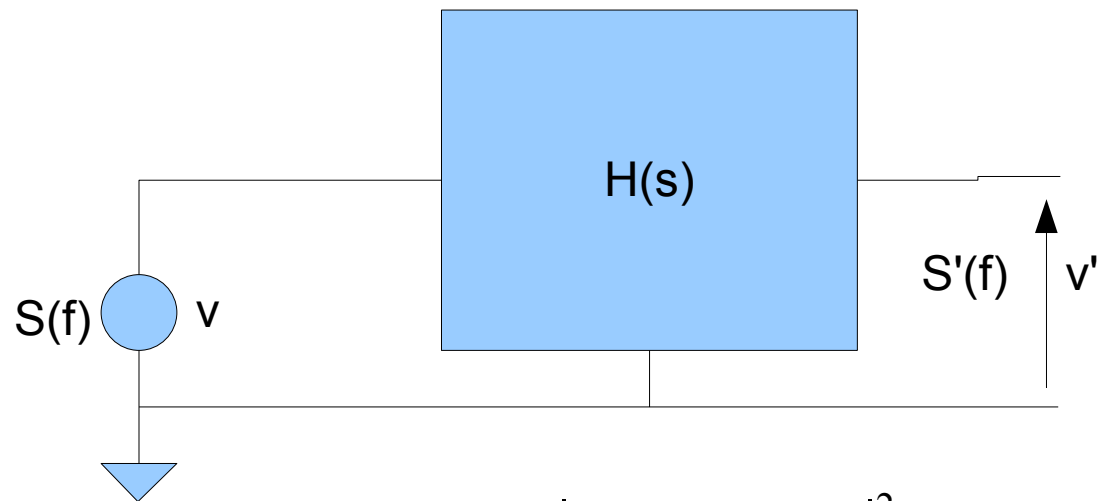
Power spectral density and RMS $v_{RMS} = \sqrt{R(0)} = \sqrt{\int_{f=0}^{\infty} S(f) df}$

Noise and linear filter

White noise

$S(f) = \text{constant}$

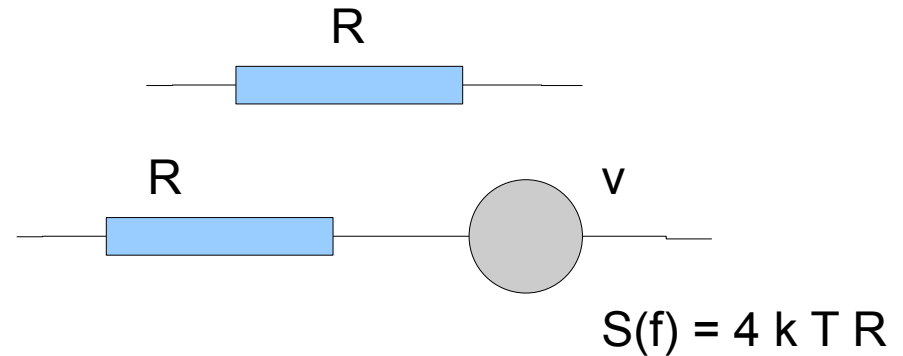
$R \sim \text{Dirac function}$



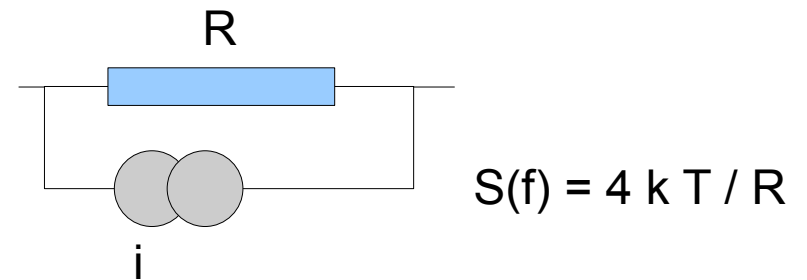
$$S'(f) = |H(j2\pi f)|^2 S(f)$$

Physical noise sources

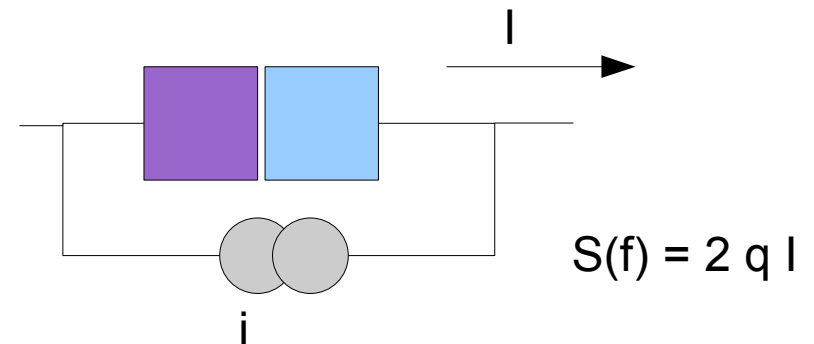
Thermal (Johnson or Nyquist) noise in resistors (white noise)



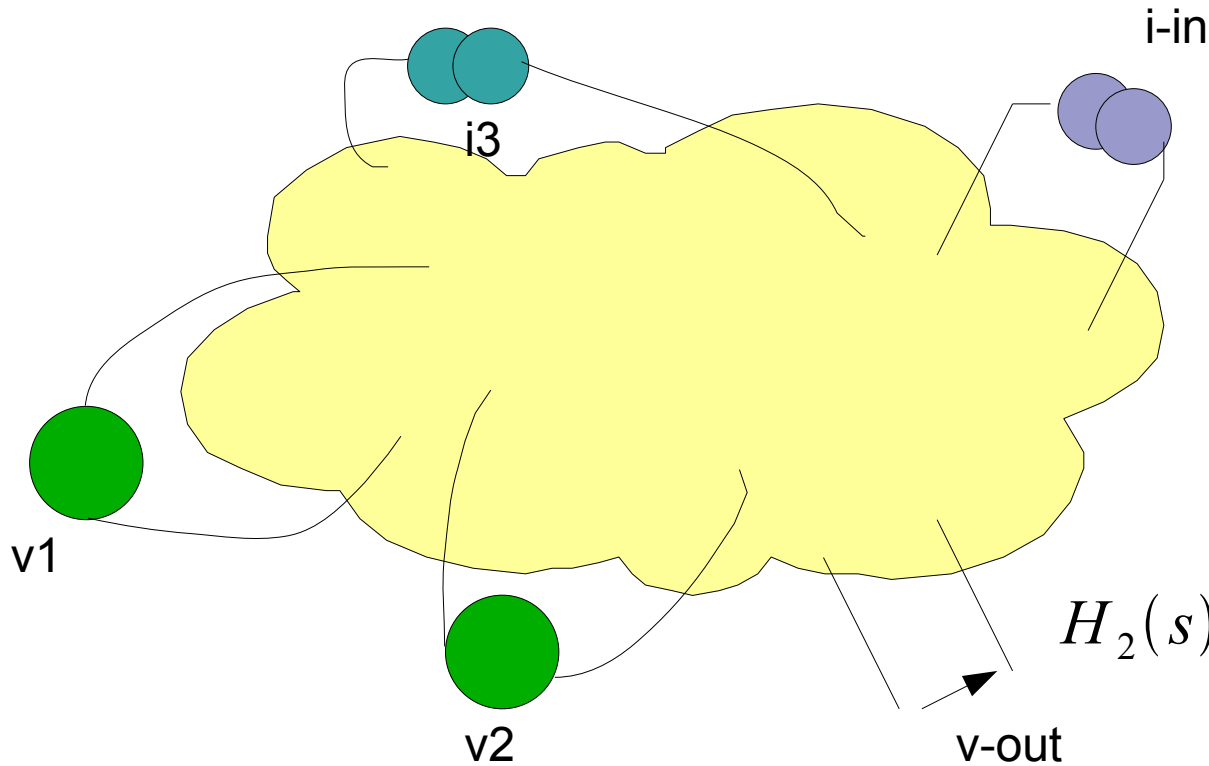
Shot noise in PN barriers (white noise)



Flicker noise, $1/f$ noise, pink noise



Networks with noise sources.

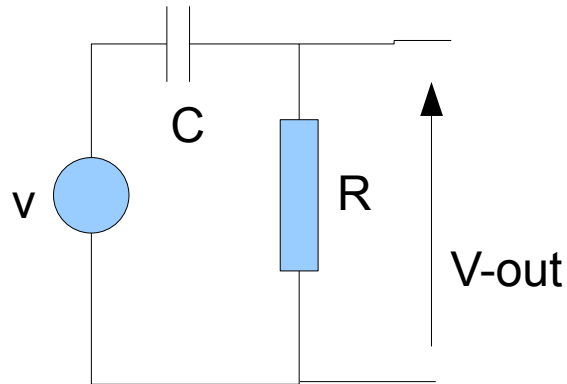


$$V_{out}(s) = H_1(s)V_1(s) + \dots + H_2(s)V_2(s) + Z_3(s)I_3(s) + \underline{Z(s)I_i(s)}$$

$$S_{out}(f) = |H_1(j2\pi f)|^2 S_1(f) + |H_2(j2\pi f)|^2 S_2(f) + |Z_3(j2\pi f)|^2 S_3(f)$$

$$S_{equi}(f) = \frac{S_{out}(f)}{|Z(j2\pi f)|^2}$$

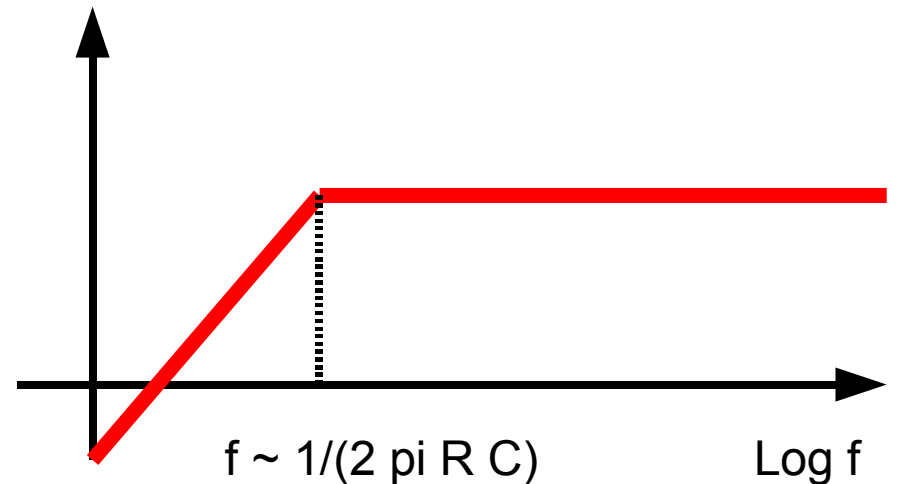
Example 1



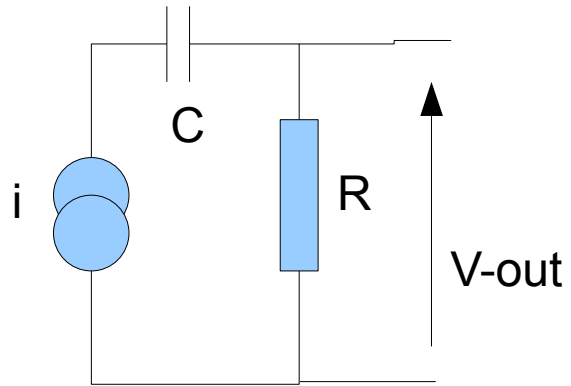
$$V_{out}(s) = \frac{R}{R + \frac{1}{sC}} V_i = \frac{RCs}{1 + RCs} V_i$$

$$|H(j2\pi f)|^2 = \left| \frac{j2\pi f RC}{1 + j2\pi f RC} \right|^2 = \frac{4\pi^2 f^2 R^2 C^2}{1 + 4\pi^2 f^2 R^2 C^2}$$

$$S'(f) = \frac{4\pi^2 f^2 R^2 C^2}{1 + 4\pi^2 f^2 R^2 C^2} S(f)$$



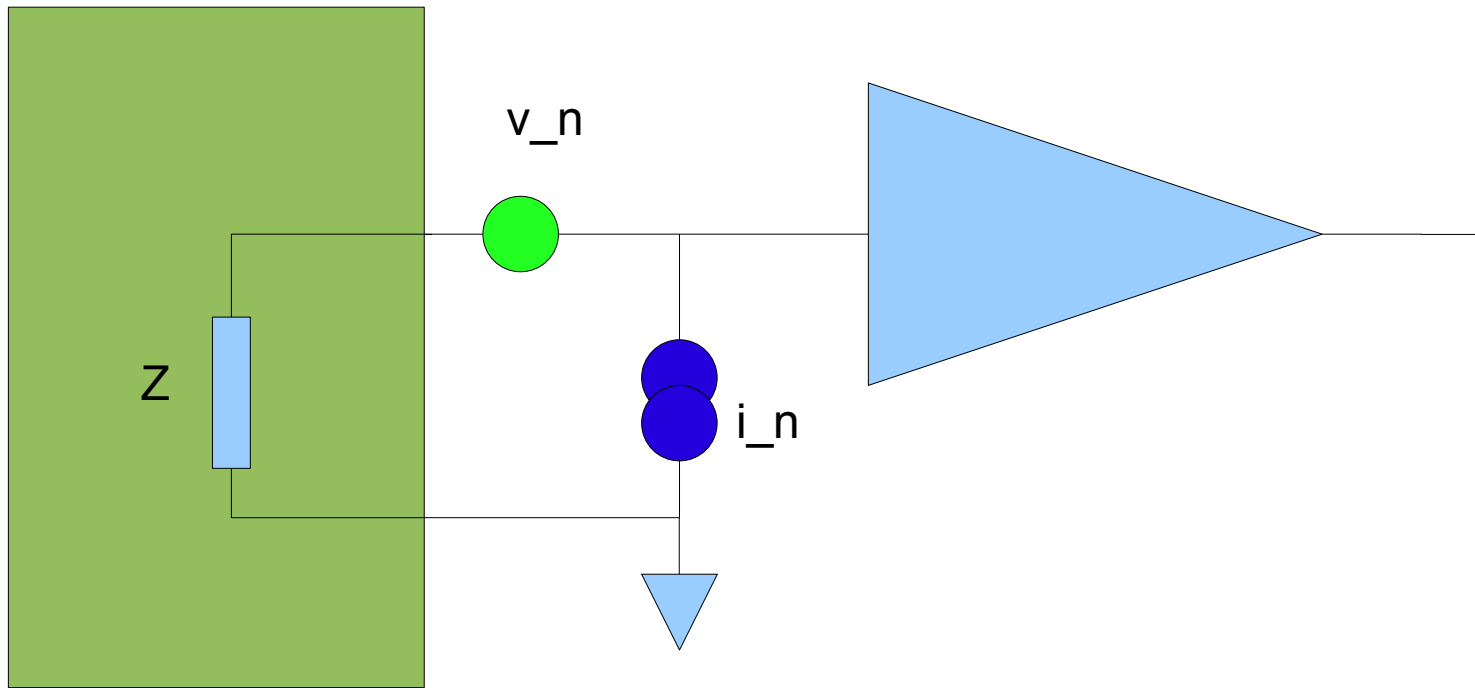
Example 2 (exercise)



$$V_{out}(s) = RI(s)$$

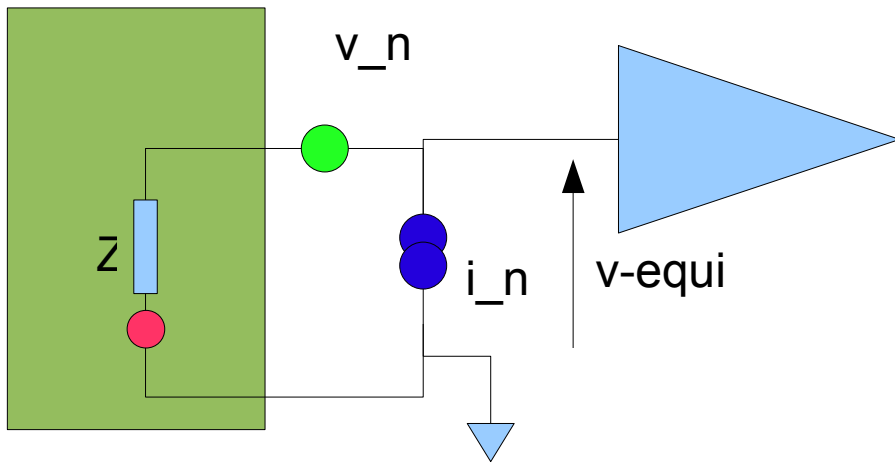
$$S'(f) = ?$$

Equivalent noise of amplifier



Equivalent noise of amplifier II

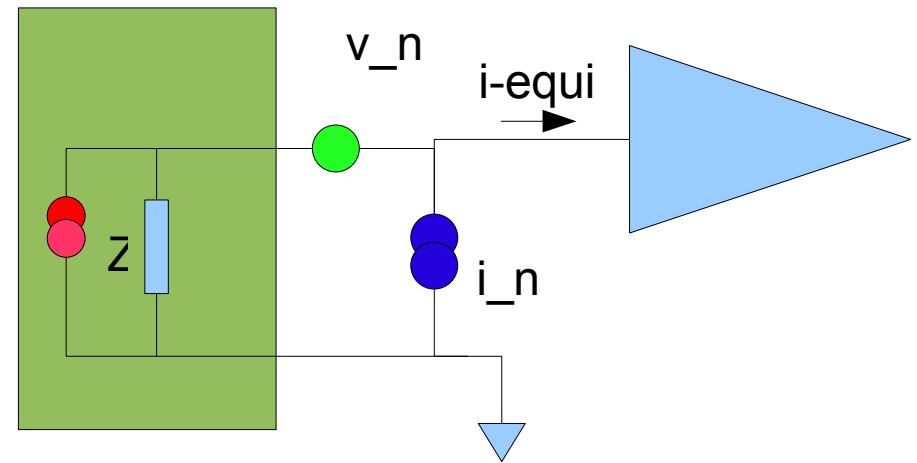
Case of voltage amplifier (Thevenin)



$$v_{equi}(s) = v_n(s) + Z(s)i_n(s)$$

$$S_{equi}(f) = S_{v_n}(f) + |Z(j2\pi f)|^2 S_{i_n}(f)$$

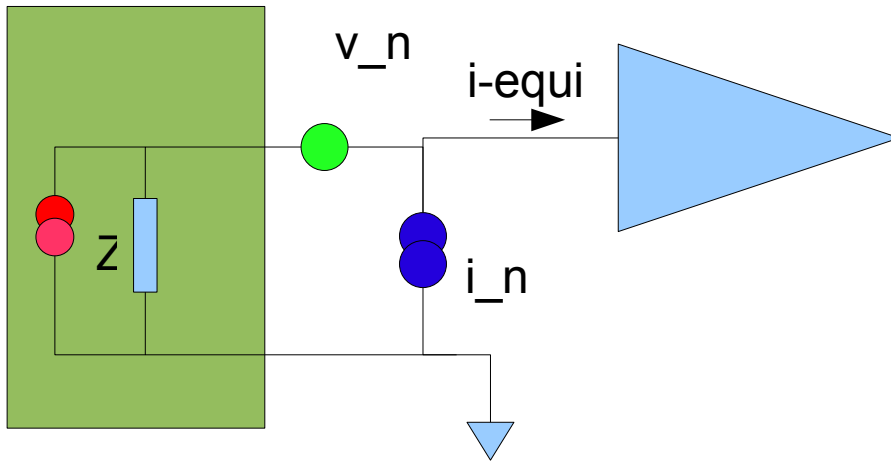
Case of current amplifier (Norton)



$$i_{equi}(s) = i_n(s) + \frac{v_n(s)}{Z(s)}$$

$$S_{equi}(f) = S_{i_n}(f) + \frac{S_{v_n}(f)}{|Z(j2\pi f)|^2}$$

Equivalent noise of amplifier III



$$S_{equi}(f) = S_{i_n}(f) + \frac{S_{v_n}(f)}{|Z(j2\pi f)|^2}$$

Load is capacitive: $Z = \frac{1}{sC}$

$$S_{equi}(f) = S_{i_n}(f) + 4\pi^2 f^2 S_{v_n}(f)$$

Load is resistive: $Z = R$

$$S_{equi}(f) = S_{i_n}(f) + \frac{S_{v_n}(f)}{R^2}$$

Shaping

Shaping for charge: impulse response of overall circuit

long enough to « integrate » the charge

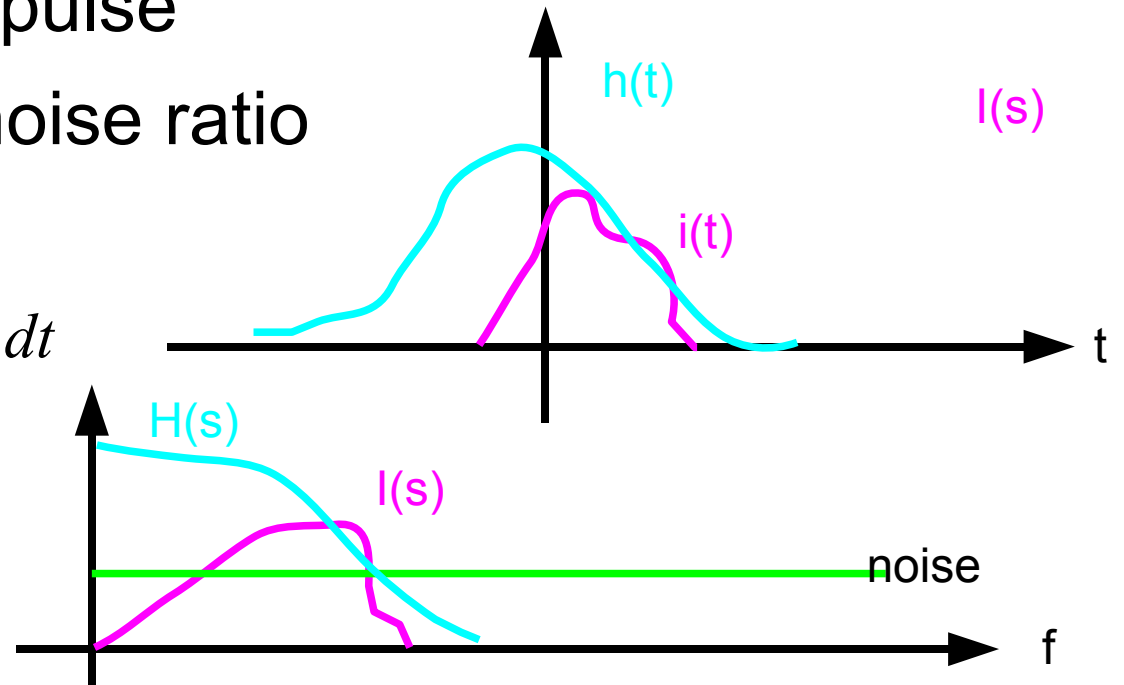
short enough to limit « dead time »

signal = maximum of pulse

best possible signal/noise ratio

$$v_{out}(t) = \int_{\tau=-\infty}^t i(\tau) h(t-\tau) dt$$

$$V(s) = H(s) I(s)$$

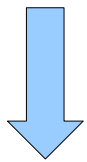


Shaping and scaling

A « unit charge » will generate an impulse response of which the height is the « gain » of the amplifier chain.

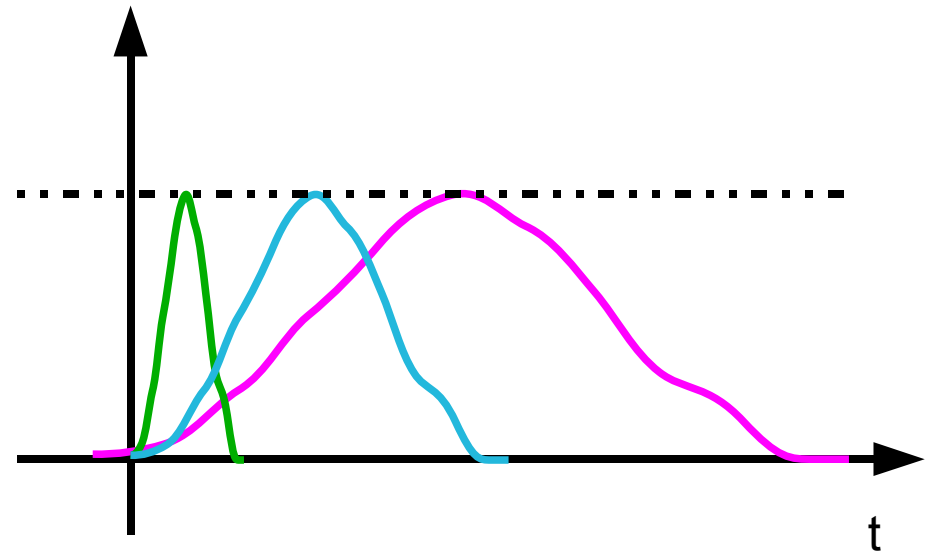
Scaling the time axis (k times faster), but keeping the gain (maximum value):

$$h(t) \rightarrow h'(t) = h(kt)$$

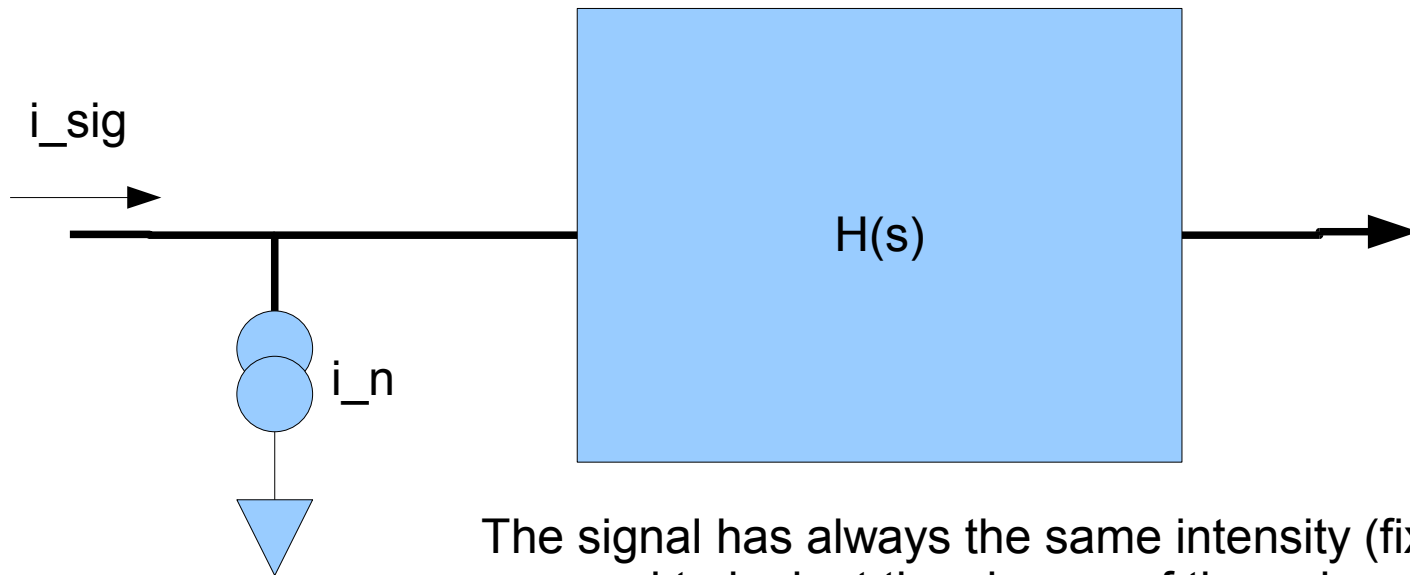


$$H(s) = \int_0^{\infty} h(t) e^{-st} dt$$

$$H(s) \rightarrow H'(s) = \frac{1}{|k|} H\left(\frac{s}{k}\right)$$



Application: scaling of S/N 1



The signal has always the same intensity (fixed gain)
we need to look at the change of the noise as a function of
time scale.

Noise = RMS value of noise (to be compared with peak signal)

$$N_1 = \sqrt{\int_{f=0}^{\infty} |H(j 2 \pi f)|^2 S(f) df}$$

$$N_2 = \frac{1}{k} \sqrt{\int_{f=0}^{\infty} |H(j 2 \pi \frac{f}{k})|^2 S(f) df}$$

$$= \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{\infty} |H(j 2 \pi u)|^2 S(k u) du}$$

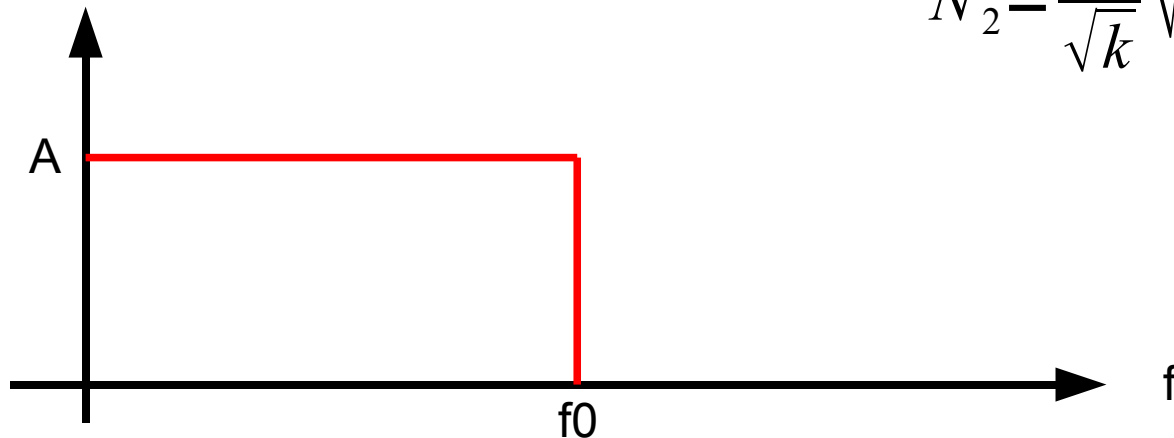
$$f/k = u$$

Scaling of S/N 2

Let us assume a very simple filter: perfect lowpass filter (with sinc response):

$f < f_0$ then $|H(f)| = A$

$f > f_0$ then $H(f) = 0$



$$N_1 = \sqrt{\int_{f=0}^{\infty} |H(j2\pi f)|^2 S(f) df}$$

$$N_1 = \sqrt{\int_{f=0}^{f_0} A^2 S(f) df}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{\infty} |H(j2\pi u)|^2 S(ku) du}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{f_0} A^2 S(ku) du}$$

Scaling of S/N 3

Case of **resistive load**

$$S_{equi}(f) = S_{i_n}(f) + \frac{S_{v_n}(f)}{R^2} = S_n$$

assume white equivalent
noise sources

$$N_1 = \sqrt{\int_{f=0}^{f_0} A^2 S(f) df}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{f_0} A^2 S(ku) du}$$

$$N_1 = \sqrt{f_0 A^2 S_n}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{f_0 A^2 S_n} = \frac{N_1}{\sqrt{k}}$$

A k times FASTER amplifier has sqrt(k) times LESS noise ;
the signal-to-noise ratio IMPROVES for faster amplifiers!

Scaling of S/N 4

Capacitive load

$$S_{equi}(f) = S_{i_n}(f) + \underline{4 \pi^2 f^2 S_{v_n}(f)}$$

Assume only **voltage noise**,

$$S_{equi}(f) = 4 \pi^2 f^2 S_{v_n}$$

assume it to be white

current noise will behave as in
the « resistive case »

$$N_1 = \sqrt{\int_{f=0}^{f_0} A^2 S(f) df}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{f_0} A^2 S(ku) du}$$

$$N_1 = \sqrt{\int_{f=0}^{f_0} A^2 4 \pi^2 f^2 S_{v_n} df} = 2 \pi A \sqrt{S_{v_n} \frac{f_0^3}{3}}$$

$$N_2 = \frac{1}{\sqrt{k}} \sqrt{\int_{u=0}^{f_0} A^2 4 \pi^2 k^2 u^2 S_{v_n} du} = \sqrt{k} \sqrt{\int_{u=0}^{f_0} A^2 4 \pi^2 u^2 S_{v_n} du} = \sqrt{(k)} N_1$$

This time, a k times FASTER amplifier has sqrt(k) times MORE noise ;
a faster amplifier DETERIORATES the S/N ratio.

Scaling of S/N 5

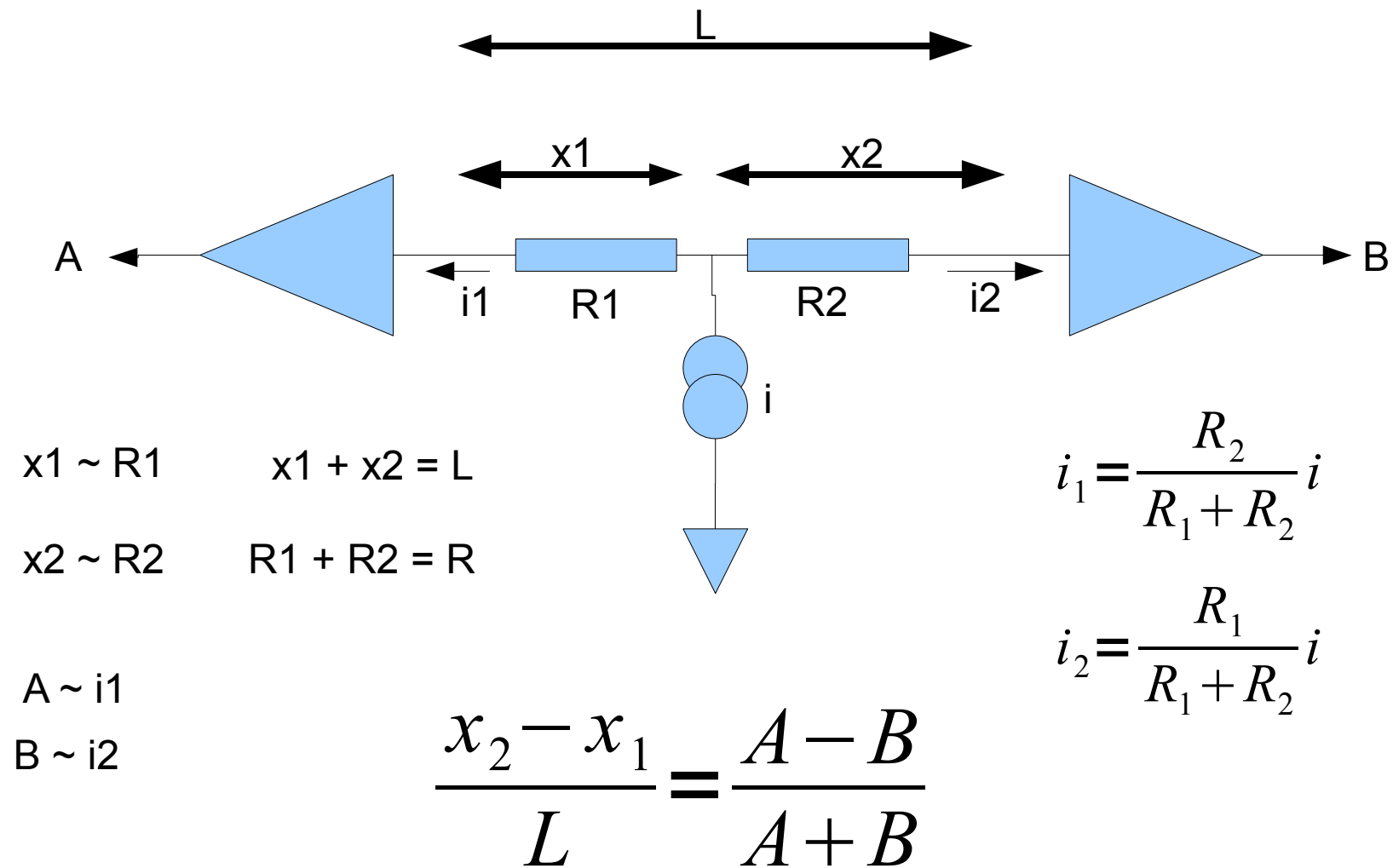
Current noise at the input: a faster amplifier
IMPROVES S/N

Voltage noise with resistive load: a faster
amplifier IMPROVES S/N

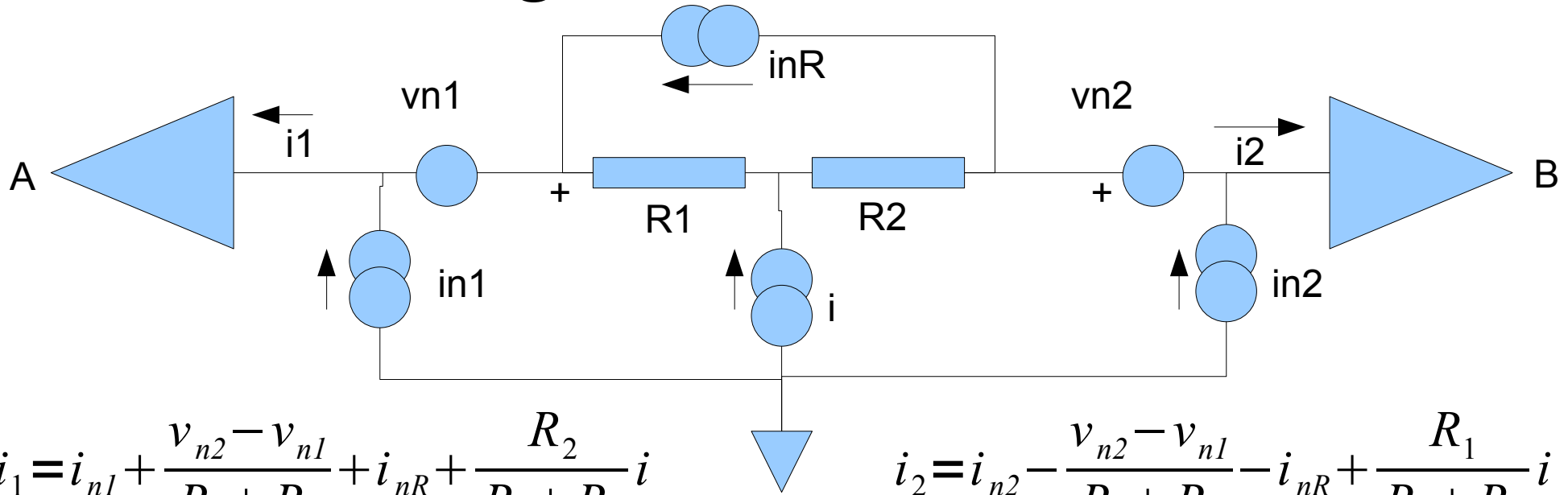
Voltage noise with capacitive load: a faster
amplifier DETERIORATES S/N

Mixed case: it depends on the relative
contributions: *there will be an optimum amplifier
speed.*

Resistive charge division: principle



Charge division: noise.



$$i_1 = i_{n1} + \frac{v_{n2} - v_{n1}}{R_1 + R_2} + i_{nR} + \frac{R_2}{R_1 + R_2} i$$

$$i_2 = i_{n2} - \frac{v_{n2} - v_{n1}}{R_1 + R_2} - i_{nR} + \frac{R_1}{R_1 + R_2} i$$

$$i_1 - i_2 = i_{n1} - i_{n2} + 2 \frac{v_{n2} - v_{n1}}{R_1 + R_2} + 2 i_{nR} + \frac{R_2 - R_1}{R_1 + R_2} i$$

$$i_1 + i_2 = i_{n1} + i_{n2} + i$$

$$S_{min} = S_i + S_i + \frac{4}{R^2} (S_v + S_v) + 4 S_R = 2 S_i + \frac{8 S_v}{R^2} + \frac{16 k T}{R}$$

$$S_{plus} = 2 S_i$$

Charge division: resolution

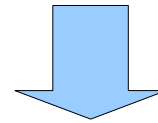
$$\delta_{rms} D = \sqrt{\int_{f=0}^{\infty} |H|^2 S_{min} df}$$

$$\delta_{rms} S = \sqrt{\int_{f=0}^{\infty} |H|^2 S_{plus} df}$$

$$p = \frac{D}{S} \quad \text{Relative position from -1 to 1.}$$

$$dp = \frac{dD}{S} - \frac{D}{S} \frac{dS}{S} = \frac{1}{S} (dD - p dS)$$

$$x = \frac{p}{2} L \quad \text{Physical position}$$



$$\delta_{rms} p = \frac{1}{S} \sqrt{(\delta_{rms} D)^2 + p^2 (\delta_{rms} S)^2}$$

$$\delta_{rms} x = \frac{L}{2S} \sqrt{(\delta_{rms} D)^2 + p^2 (\delta_{rms} S)^2}$$

Position resolution (1 sigma)